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Accession number:20123115291272

Title:Gigabyte and terabyte per second connections with semiconductor waveguide technology

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Source title: Microwave and Optical Technology Letters

Abbreviated source title: Microwave Opt Technol Lett

Volume:54

Issue:10

Issue date: October 2012

Publication year:2012

Pages:2438-2444

Language:English

ISSN:08952477

E-ISSN:10982760

CODEN:MOTLEO

Document type:Journal article (JA)

Publisher:John Wiley and Sons Inc., P.O.Box 18667, Newark, NJ 07191-8667, United States

Abstract:This work presents the research, design, and development of guided-wave connections in SiGe semiconductor substrates.The integration of digital systems using semiconductor integrated waveguides (S-SIWG) with QAM modulation formats are highlighted for ultrafast inter-chip and intra-chip connections at 100 Gbit/s extended to the Terahertz domain. The simulations of the frequency response for the prototype model with coaxial probe excitations in the frequency range 50-150 GHz are evaluated, showing far than satisfactory performance. The S-SIWG is then simulated in the 0.5-1.5 THz bandwidth, presenting excellent insertion loss. A SiGe S-SIWG prototype was fabricated and tested at 15-60 GHz. © 2012 Wiley Periodicals, Inc.

Number of references:14

Main heading:Computer simulation

Controlled terms:Frequency response - Integrated circuits - Networks (circuits) - Silicon alloys

Uncontrolled terms:Coaxial probe - Digital system - Frequency ranges - High-speed - Integrated waveguides - Inter-chip - Modulation formats - Prototype models - Semiconductor waveguide - SiGe - SiGe Semiconductors - Terahertz domains - Ultra-fast

Classification code:549.3 Nonferrous Metals and Alloys excluding Alkali and Alkaline Earth Metals - 703.1 Electric Networks - 714.2 Semiconductor Devices and Integrated Circuits - 723.5

Computer Applications

DOI:10.1002/mop.27060

Database:Compendex

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